

Supporting Information

Automated Manufacturing of Segmented Nanowires with Thin Ferromagnetic Layers: a Step Towards Miniature SFS Josephson Junctions

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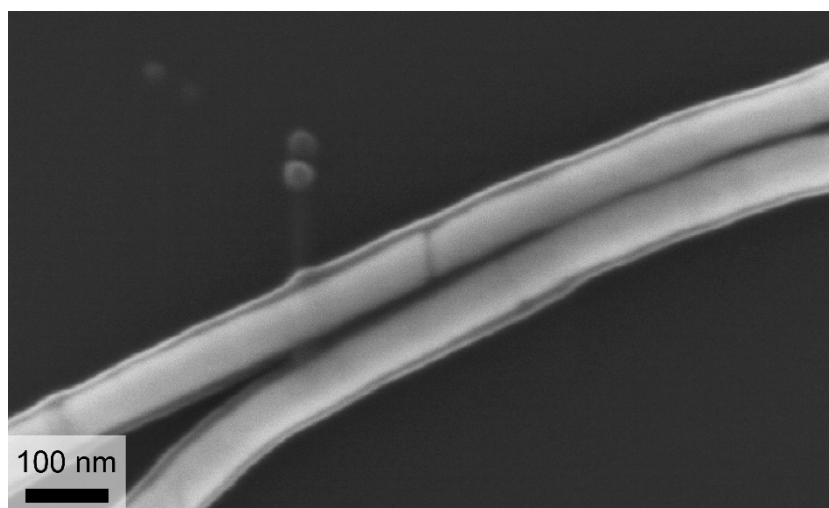


Figure S1. SEM image of individual segmented Au/Ni/Au nanowires covered by a thin layer of polyvinylpyrrolidone.

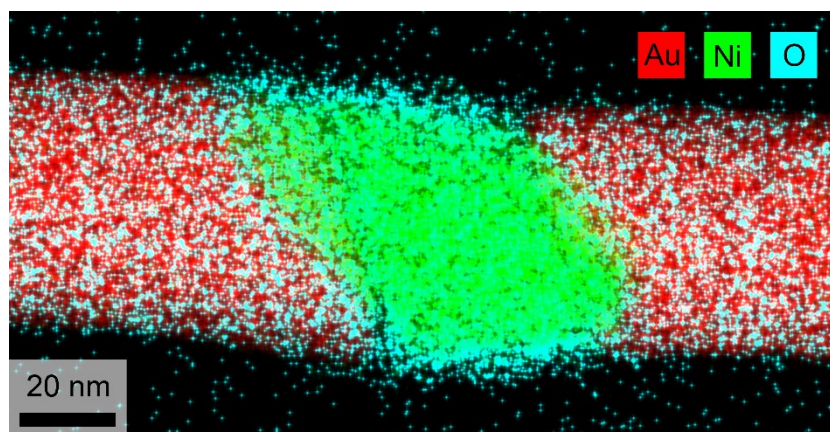


Figure S2. EDS elemental maps showing the local distribution of gold (red), nickel (green), and oxygen (blue) in Au/Ni/Au nanowires in the region of a ferromagnetic segment with a length of 46 nm. The data were obtained after a year-long storage of nanowires suspended in isopropanol.

Superconducting transport in the SNFNS bridge

We consider the superconducting properties of the SNFNS nanowire bridge within the framework of the Usadel equations¹ in a semi-one-dimensional approach, similar to Refs.^{2,3} We assume that the dirty limit condition is met for all metals, the critical temperature of the weak link materials is zero, and the nanowire diameter d is much less than the coherence length of the bulk normal metal, $\xi_n = (\hbar D_n / 2\pi k_B T_c)^{1/2}$, where D_n is the diffusion coefficient of normal metal N and T_c is the critical temperature of planar electrodes S.

Superconductivity in the system arises owing to the proximity effect between the superconducting electrode S and the normal layer N beneath it. The electronic structure of the N-layer regions under the S-electrode is described by the modified Usadel equation:

$$\xi_{eff}^2 \frac{\partial}{\partial x} \left(G_n^2 \frac{\partial \Phi_n}{\partial x} \right) - \Phi_n = -\delta \exp(i\chi),$$

$$\xi_{eff}^2 = \frac{\xi_n^2 \gamma_{BM}}{G_n(G_s + \gamma_{BM}\omega)}, \quad \delta = \frac{G_s \Delta}{(G_s + \gamma_{BM}\omega)}.$$

Here, Φ_n , $F_n = \Phi_{n,\omega} / (\omega^2 + \Phi_{n,\omega} \Phi_{n,-\omega}^*)^{-1/2}$, $G_n = \omega / (\omega^2 + \Phi_{n,\omega} \Phi_{n,-\omega}^*)^{-1/2}$, and $G_s = \omega / (\omega^2 + \Delta^2)^{-1/2}$ are the Usadel Green's functions, $\omega = (2n + 1)T/T_c$ are the Matsubara frequencies normalized by πT_c , γ_{BM} is the boundary parameter at the SN interface, x is the coordinate normalized by ξ_n , and Δ is the modulus of the order parameter in the S electrode normalized by $\pi k_B T_c$.

The region between the S electrodes is described as:

$$\xi_n^2 \frac{\partial}{\partial x} \left(G_n^2 \frac{\partial \Phi_n}{\partial x} \right) - \omega G_n \Phi_n = 0,$$

$$\xi_f^2 \frac{\partial}{\partial x} \left(G_f^2 \frac{\partial \Phi_f}{\partial x} \right) - \tilde{\omega} G_f \Phi_f = 0.$$

for the N and F parts of the nanowire, respectively, with boundary conditions⁴ at the NF and FN interfaces

$$\pm \gamma_B \xi_n G_n \frac{d}{dx} \Phi_n = G_f \left(\frac{\omega}{\tilde{\omega}} \Phi_f - \Phi_n \right),$$

$$\mp \gamma_B \gamma \xi_f G_f \frac{d}{dx} \Phi_f = G_n \left(\frac{\tilde{\omega}}{\omega} \Phi_n - \Phi_f \right).$$

Here, $\tilde{\omega}_p = \omega + iH$, where H is the exchange energy of the F-layer normalized by πT_c . $\gamma_B = R_B A_B / \rho_n \xi_n$ and $\gamma = \rho_n \xi_n / \rho_f \xi_f$ are the suppression parameters of the interface, where ξ_n , ξ_f , ρ_n , and ρ_f represent the coherence lengths and resistivities of the N and F materials,

respectively. R_B and A_B are the resistance and cross-sectional area of the corresponding interface, respectively.

The current in the N-part of the nanowire is

$$I = \frac{\pi k_B T A_B}{2e \xi_n \rho_n} \sum_{-\infty}^{\infty} \frac{G_n^2}{\omega^2} \left(\Phi_{n,-\omega}^* \frac{\partial \Phi_{n,\omega}}{\partial x} - \Phi_{n,\omega} \frac{\partial \Phi_{n,-\omega}^*}{\partial x} \right).$$

In some specific cases, the dirty limit is not applicable to the system. This can make the problem more complex and require the solution of a hybrid boundary problem involving the Usadel and Eilenberger equations.^{5,6}

References

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